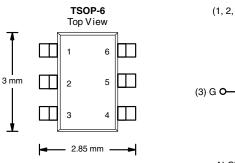
SQ3460EV

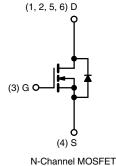


Vishay Siliconix

Automotive N-Channel 20 V (D-S) 175 °C MOSFET

PRODUCT SUMMARY				
V _{DS} (V)	20			
$R_{DS(on)} (\Omega)$ at $V_{GS} = 4.5 V$	0.030			
$R_{DS(on)}(\Omega)$ at $V_{GS} = 2.5 V$	0.034			
$R_{DS(on)} (\Omega)$ at $V_{GS} = 1.8 V$	0.038			
I _D (A)	8			
Configuration	Single			





FEATURES

- Halogen-free According to IEC 61249-2-21
 Definition
- TrenchFET[®] Power MOSFET
- AEC-Q101 Qualified^d
- 100 % $R_{\rm q}$ and UIS Tested
- Compliant to RoHS Directive 2002/95/EC



KOHS COMPLIANT HALOGEN FREE

Marking Code: 8Jxxx

ORDERING INFORMATION			
Package	TSOP-6		
Lead (Pb)-free and Halogen-free	SQ3460EV-T1-GE3		

ABSOLUTE MAXIMUM RATINGS (T _C = 25 °C, unless otherwise noted)				
PARAMETER	SYMBOL	LIMIT	UNIT	
Drain-Source Voltage	V _{DS}	20	V	
Gate-Source Voltage	V _{GS}	± 8	v	
Continuous Drain Current	$T_C = 25 \ ^{\circ}C^a$	1	8	
Continuous Drain Current	T _C = 125 °C	I _D	4.8	
Continuous Source Current (Diode Conduction)	I _S	4.6	А	
Pulsed Drain Current ^b		I _{DM}	32	
Single Pulse Avalanche Current	L = 0.1 mH	I _{AS}	10	
Single Pulse Avalanche Energy	L = 0.1 mm	E _{AS}	5	mJ
Maximum Power Dissipation ^b	T _C = 25 °C	P _D	3.6	w
	T _C = 125 °C		1.2	~~
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to + 175	°C

THERMAL RESISTANCE RATINGS					
PARAMETER		SYMBOL	LIMIT	UNIT	
Junction-to-Ambient	PCB Mount ^c	R _{thJA}	110	°C/W	
Junction-to-Foot (Drain)		R _{thJF}	41	0/10	

Notes

a. Package limited.

b. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

c. When mounted on 1" square PCB (FR-4 material).

d. Parametric verification ongoing.

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SQ3460EV

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PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
Static					•		
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS} = 0, I_D = 250 \ \mu A$		20	-	-	v
Gate-Source Threshold Voltage	V _{GS(th)}	V _{DS} =	= V _{GS} , I _D = 250 μA	0.4	0.6	1.0	v
Gate-Source Leakage	I _{GSS}	V _{DS} =	= 0 V, V _{GS} = ± 8 V	-	-	± 100	nA
		$V_{GS} = 0 V$	V _{DS} = 20 V	-	-	1	μA
Zero Gate Voltage Drain Current	I _{DSS}	$V_{GS} = 0 V$	$V_{DS} = 20 \text{ V}, \text{ T}_{J} = 125 ^{\circ}\text{C}$	-	-	50	
		$V_{GS} = 0 V$	$V_{DS} = 20 \text{ V}, \text{ T}_{J} = 175 ^{\circ}\text{C}$	-	-	150	
On-State Drain Current ^a	I _{D(on)}	$V_{GS} = 4.5 V$	$V_{DS} \ge 5 V$	10	-	-	Α
		$V_{GS} = 4.5 V$	I _D = 5.1 A	-	0.025	0.030	
		$V_{GS} = 4.5 V$	I _D = 5.1 A, T _J = 125 °C	-	-	0.045	Ω
Drain-Source On-State Resistance ^a	R _{DS(on)}	$V_{GS} = 4.5 V$	I _D = 5.1 A, T _J = 175 °C	-	-	0.053	
		$V_{GS} = 2.5 V$	I _D = 4.7 A	-	0.027	0.034	
		V _{GS} = 1.8 V	I _D = 2.5 A	-	0.031	0.038	
Forward Transconductanceb	9 _{fs}	V _{DS} :	= 15 V, I _D = 5.1 A	-	28	-	S
Dynamic ^b		<u>.</u>					
Input Capacitance	C _{iss}		_{GS} = 0 V V _{DS} = 10 V, f = 1 MHz	-	848	1060	pF
Output Capacitance	C _{oss}	$V_{GS} = 0 V$		-	117	146	
Reverse Transfer Capacitance	C _{rss}			-	68	85	
Total Gate Charge ^c	Qg			-	9.3	14	
Gate-Source Charge ^c	Q _{gs}	$V_{GS} = 4.5 V$	$V_{\rm GS} = 4.5 \ {\rm V}$ $V_{\rm DS} = 10 \ {\rm V}, \ {\rm I}_{\rm D} = 5.1 \ {\rm A}$	-	1.1	-	nC
Gate-Drain Charge ^c	Q _{gd}			-	1.4	-	
Gate Resistance	Rg		f = 1 MHz		12.4	18.6	Ω
Turn-On Delay Time ^c	t _{d(on)}			-	8	12	
Rise Time ^c	t _r	$V_{DD} = 10 \text{ V}, \text{ R}_{\text{L}} = 10 \Omega$ $I_{\text{D}} \cong 1 \text{ A}, \text{ V}_{\text{GEN}} = 4.5 \text{ V}, \text{ R}_{\text{g}} = 1 \Omega$		-	8	12	
Turn-Off Delay Time ^c	t _{d(off)}			-	21	32	ns
Fall Time ^c	t _f			-	8	12	
Source-Drain Diode Ratings and Chara	acteristics ^b						
Pulsed Current ^a	I _{SM}			-	-	32	А
Forward Voltage	V _{SD}	I _F	= 5 A, V _{GS} = 0	-	0.77	1.2	V

Notes

a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

b. Guaranteed by design, not subject to production testing.

c. Independent of operating temperature.

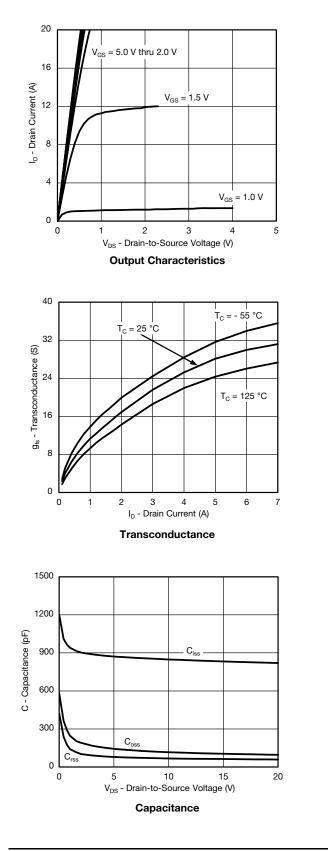
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

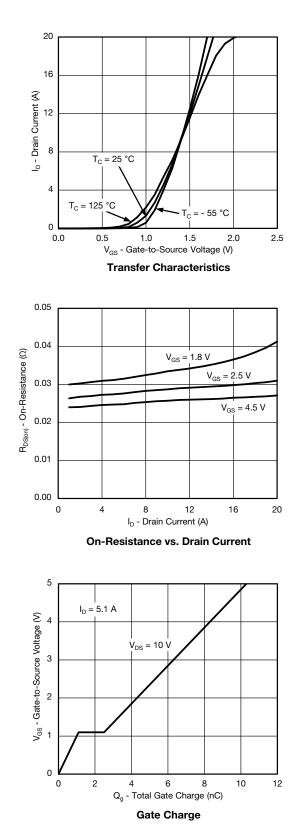
S11-2359-Rev. D, 05-Dec-11



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TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)





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3

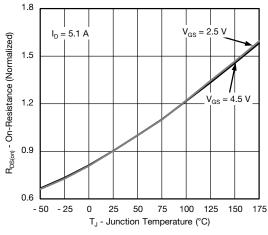
Document Number: 67037



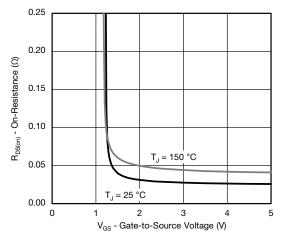
SQ3460EV

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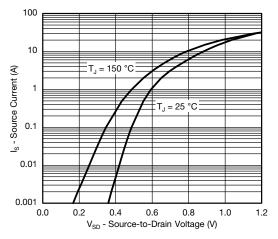
TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)



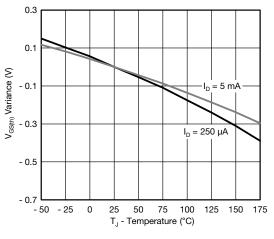
On-Resistance vs. Junction Temperature



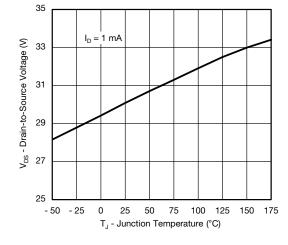
On-Resistance vs. Gate-to-Source Voltage

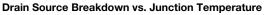


Source Drain Diode Forward Voltage







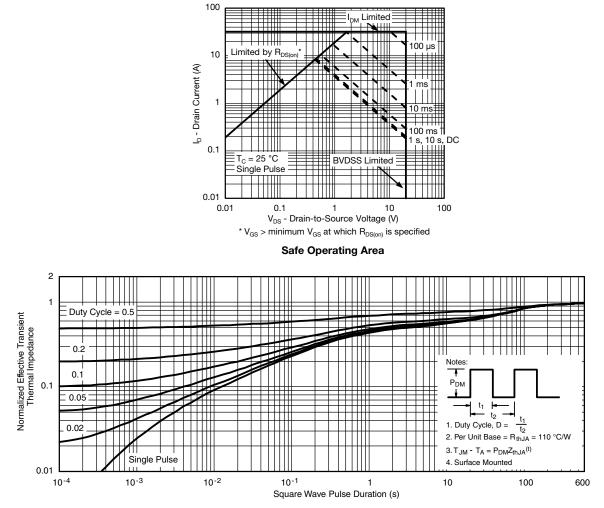


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THERMAL RATINGS ($T_A = 25 \text{ °C}$, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient

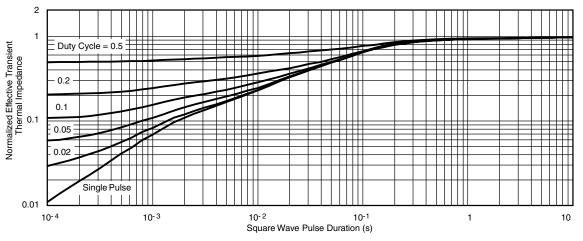
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SQ3460EV

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THERMAL RATINGS ($T_A = 25 \text{ °C}$, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Foot

Note

• The characteristics shown in the two graphs

- Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)

- Normalized Transient Thermal Impedance Junction-to-Foot (25 °C)

are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg267037.



Package Information

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TSOP: 5/6-LEAD JEDEC Part Number: MO-193C









6-LEAD TSOP



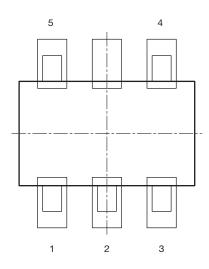
	MILLIMETERS			INCHES			
Dim	Min	Nom	Max	Min	Nom	Max	
Α	0.91	-	1.10	0.036	-	0.043	
A ₁	0.01	-	0.10	0.0004	-	0.004	
A ₂	0.90	-	1.00	0.035	0.038	0.039	
b	0.30	0.32	0.45	0.012	0.013	0.018	
С	0.10	0.15	0.20	0.004	0.006	0.008	
D	2.95	3.05	3.10	0.116	0.120	0.122	
Е	2.70	2.85	2.98	0.106	0.112	0.117	
E ₁	1.55	1.65	1.70	0.061	0.065	0.067	
е		0.95 BSC			0.0374 BSC		
e ₁	1.80	1.90	2.00	0.071	0.075	0.079	
L	0.32	-	0.50	0.012	-	0.020	
L ₁		0.60 Ref			0.024 Ref		
L ₂	0.25 BSC				0.010 BSC		
R	0.10	-	-	0.004	-	-	
θ	0°	4°	8°	0°	4°	8°	
θ_1	7° Nom				7° Nom		
ECN: C-06593-Rev. I, 18-Dec-06 DWG: 5540							

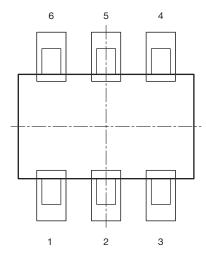
PAD Pattern



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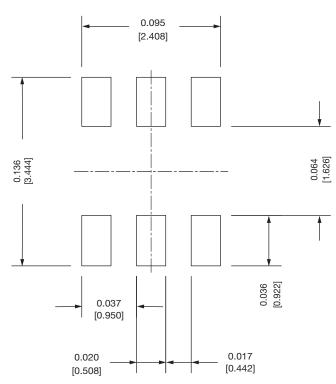
Recommended Land Pattern For TSOP-5L / TSOP-6L





TSOP 5L





Note

• All dimensions are in inches (millimeter)

ECN: C22-0860-Rev. B, 24-Oct-2022	
DWG: 3010	



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